

No.2198A

SB0015-03A

Schottky Barrier Diode

30V, 15mA Detection Applications

Features

- Glass sleeve structure
- · Detection efficiency: 70%
- · Small size (Half the size of the DO-35 heretofore in use)

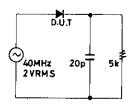
Absolute Maximum Ratings at Ta = 25°C

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Reverse Voltage	$ m V_R$	-30	V
Average Rectified Current	I_{o}	15	mA
Junction Temperature	Tj	100	$^{\circ}\mathrm{C}$
Storage Temperature	\mathbf{Tstg}	-55 to +100	$^{\circ}\mathrm{C}$

Electrical Characteristics at Ta = 25°C

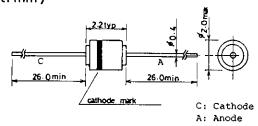
mm typ max	um
3.0	mΑ
-100	μA
3.0	ρF
70	^ %
	3.0 -100 3.0

Detection Efficiency Circuit



Unit (resistance: Ω, capacitance: F)

Package Dimensions 1153A (unit: mm)



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